

# Martti J Puska

## List of Publications by Year in Descending Order

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

224  
papers

13,157  
citations

58  
h-index

109  
g-index

231  
ext. papers

13,991  
ext. citations

4  
avg, IF

6.16  
L-index

#	Paper	IF	Citations
224	Simulating Raman spectra by combining first-principles and empirical potential approaches with application to defective MoS <sub>2</sub> . <i>Npj Computational Materials</i> , <b>2020</b> , 6,	10.9	9
223	The fox and the hound: in-depth and in-grain Na doping and Ga grading in Cu(In,Ga)Se <sub>2</sub> solar cells. <i>Journal of Materials Chemistry A</i> , <b>2020</b> , 8, 6471-6479	13	15
222	Heavy Alkali Treatment of Cu(In,Ga)Se <sub>2</sub> Solar Cells: Surface versus Bulk Effects. <i>Advanced Energy Materials</i> , <b>2020</b> , 10, 1903752	21.8	68
221	Plasmon Excitations in Mixed Metallic Nanoarrays. <i>ACS Nano</i> , <b>2019</b> , 13, 5344-5355	16.7	5
220	pH-Dependent Distribution of Functional Groups on Titanium-Based MXenes. <i>ACS Nano</i> , <b>2019</b> , 13, 9171-9181	16.7	45
219	Efficient method for calculating Raman spectra of solids with impurities and alloys and its application to two-dimensional transition metal dichalcogenides. <i>Physical Review Materials</i> , <b>2019</b> , 3,	3.2	9
218	Plasmon-Induced Direct Hot-Carrier Transfer at Metal-Acceptor Interfaces. <i>ACS Nano</i> , <b>2019</b> , 13, 3188-3195	16.7	42
217	Alkali Postdeposition Treatment-Induced Changes of the Chemical and Electronic Structure of Cu(In,Ga)Se Thin-Film Solar Cell Absorbers: A First-Principle Perspective. <i>ACS Applied Materials &amp; Interfaces</i> , <b>2019</b> , 11, 3024-3033	9.5	7
216	Electronic Transport Properties of Carbon-Nanotube Networks: The Effect of Nitrate Doping on Intratube and Intertube Conductances. <i>Physical Review Applied</i> , <b>2018</b> , 9,	4.3	5
215	Stability of Cu-Precipitates in Al-Cu Alloys. <i>Applied Sciences (Switzerland)</i> , <b>2018</b> , 8, 1003	2.6	5
214	Structural details of Al/Al <sub>2</sub> O <sub>3</sub> junctions and their role in the formation of electron tunnel barriers. <i>Physical Review B</i> , <b>2018</b> , 97,	3.3	9
213	Conductivity of AuCl <sub>4</sub> -Functionalized Carbon Nanotube Networks. <i>Journal of Physical Chemistry C</i> , <b>2017</b> , 121, 4627-4634	3.8	7
212	First-Principles Modeling of Point Defects and Complexes in Thin-Film Solar-Cell Absorber CuInSe <sub>2</sub> . <i>Advanced Electronic Materials</i> , <b>2017</b> , 3, 1600353	6.4	24
211	Modeling of electron tunneling through a tilted potential barrier. <i>Journal of Applied Physics</i> , <b>2017</b> , 121, 134304	2.5	9
210	Theory and Applications of Generalized Pipek-Mezey Wannier Functions. <i>Journal of Chemical Theory and Computation</i> , <b>2017</b> , 13, 460-474	6.4	25
209	Effect of edge plasmons on the optical properties of MoS <sub>2</sub> monolayer flakes. <i>Physical Review B</i> , <b>2017</b> , 96,	3.3	11
208	Kohn-Sham Decomposition in Real-Time Time-Dependent Density-Functional Theory: An Efficient Tool for Analyzing Plasmonic Excitations. <i>Journal of Chemical Theory and Computation</i> , <b>2017</b> , 13, 4779-4790	6.4	73

207	Effect of Alkali Metal Atom Doping on the CuInSe <sub>2</sub> -Based Solar Cell Absorber. <i>Journal of Physical Chemistry C</i> , <b>2017</b> , 121, 15516-15528	3.8	95
206	Tsu-Esaki modeling of tunneling currents in ferroelectric tunnel junctions. <i>Journal of Applied Physics</i> , <b>2017</b> , 122, 234301	2.5	3
205	Vibrational Properties of Metal Phosphorus Trichalcogenides from First-Principles Calculations. <i>Journal of Physical Chemistry C</i> , <b>2017</b> , 121, 27207-27217	3.8	36
204	Modeling positronium beyond the single particle approximation. <i>Journal of Physics B: Atomic, Molecular and Optical Physics</i> , <b>2016</b> , 49, 064005	1.3	8
203	Resistive Switching in All-Oxide Ferroelectric Tunnel Junctions with Ionic Interfaces. <i>Advanced Materials</i> , <b>2016</b> , 28, 6852-9	24	59
202	Effect of interface geometry on electron tunnelling in Al/Al <sub>2</sub> O <sub>3</sub> /Al junctions. <i>Journal Physics D: Applied Physics</i> , <b>2016</b> , 49, 165303	3	8
201	Impact of Ga-V Codoping on Interfacial Electron Transfer in Dye-Sensitized TiO <sub>2</sub> . <i>Journal of Physical Chemistry Letters</i> , <b>2015</b> , 6, 2603-7	6.4	5
200	Nanoplasmonics simulations at the basis set limit through completeness-optimized, local numerical basis sets. <i>Journal of Chemical Physics</i> , <b>2015</b> , 142, 094114	3.9	22
199	Quantized Evolution of the Plasmonic Response in a Stretched Nanorod. <i>Physical Review Letters</i> , <b>2015</b> , 115, 236804	7.4	46
198	Enhancing conductivity of metallic carbon nanotube networks by transition metal adsorption. <i>Journal of Chemical Physics</i> , <b>2015</b> , 142, 054705	3.9	10
197	Charge Transfer at the Hybrid Interfaces in the Presence of Water: A Theoretical Study. <i>Journal of Physical Chemistry C</i> , <b>2015</b> , 119, 28347-28352	3.8	5
196	Pick-off annihilation of positronium in matter using full correlation single particle potentials: solid He. <i>Journal of Physical Chemistry B</i> , <b>2015</b> , 119, 1747-55	3.4	5
195	Electronic stopping power from first-principles calculations with account for core electron excitations and projectile ionization. <i>Physical Review B</i> , <b>2014</b> , 89,	3.3	59
194	Physical Factors Affecting Charge Transfer at the Pe-COOH/TiO <sub>2</sub> Anatase Interface. <i>Journal of Physical Chemistry C</i> , <b>2014</b> , 118, 25310-25319	3.8	8
193	Full-correlation single-particle positron potentials for a positron and positronium interacting with atoms. <i>Physical Review A</i> , <b>2014</b> , 89,	2.6	10
192	First-Principles Study of Excited State Evolution in a Protected Gold Complex. <i>Journal of Physical Chemistry C</i> , <b>2013</b> , 117, 11837-11842	3.8	6
191	Modeling Bi-induced changes in the electronic structure of GaAs <sub>1-x</sub> Bi <sub>x</sub> alloys. <i>Physical Review B</i> , <b>2013</b> , 88,	3.3	19
190	Origin of band gap bowing in dilute GaAs <sub>1-x</sub> N <sub>x</sub> and GaP <sub>1-x</sub> N <sub>x</sub> alloys: A real-space view. <i>Physical Review B</i> , <b>2013</b> , 88,	3.3	19

189	Exchange and correlation effects in the strongly interacting He-Ps system. <i>Journal of Physics: Conference Series</i> , <b>2013</b> , 443, 012004	0.3	1
188	Hybrid functional study of band structures of GaAs <sub>1-x</sub> N <sub>x</sub> and GaSb <sub>1-x</sub> N <sub>x</sub> alloys. <i>Physical Review B</i> , <b>2012</b> , 85,	3.3	24
187	Electronic transport in graphene-based structures: An effective cross-section approach. <i>Physical Review B</i> , <b>2012</b> , 85,	3.3	11
186	Ab initio transport fingerprints for resonant scattering in graphene. <i>Physical Review B</i> , <b>2012</b> , 86,	3.3	10
185	Matter-positronium interaction: A study of the He-atom-positronium system. <i>Physical Review A</i> , <b>2012</b> , 85,	2.6	7
184	Native point defect energetics in GaSb: Enabling p-type conductivity of undoped GaSb. <i>Physical Review B</i> , <b>2012</b> , 86,	3.3	32
183	Nonadiabatic Ehrenfest molecular dynamics within the projector augmented-wave method. <i>Journal of Chemical Physics</i> , <b>2012</b> , 136, 144103	3.9	32
182	Study of Unbound HePs Using Exact Diagonalization Technique. <i>Materials Science Forum</i> , <b>2012</b> , 733, 38-42.	0.4	4
181	Electron transport in edge-disordered graphene nanoribbons. <i>Physical Review B</i> , <b>2011</b> , 83,	3.3	25
180	Local semiconducting transition in armchair carbon nanotubes: The effect of periodic bi-site perturbation on electronic and transport properties of carbon nanotubes. <i>Physical Review B</i> , <b>2011</b> , 83,	3.3	4
179	Nano-structures in Al-based alloys. <i>Journal of Physics: Conference Series</i> , <b>2011</b> , 265, 012017	0.3	1
178	Bound and free self-interstitial defects in graphite and bilayer graphene: A computational study. <i>Physical Review B</i> , <b>2011</b> , 84,	3.3	31
177	Clustering and conductance in breakage of sodium nanowires. <i>Physical Review B</i> , <b>2011</b> , 83,	3.3	2
176	Boston et al. Reply:. <i>Physical Review Letters</i> , <b>2011</b> , 106,	7.4	11
175	All-electron time-dependent density functional theory with finite elements: time-propagation approach. <i>Journal of Chemical Physics</i> , <b>2011</b> , 135, 154104	3.9	12
174	Positrons as interface-sensitive probes of polar semiconductor heterostructures. <i>Physical Review B</i> , <b>2010</b> , 82,	3.3	20
173	Adsorption structures of phenol on the Si(001)(2x1) surface calculated using density functional theory. <i>Physical Review B</i> , <b>2010</b> , 81,	3.3	15
172	Generalized tight-binding transport model for graphene nanoribbon-based systems. <i>Physical Review B</i> , <b>2010</b> , 81,	3.3	106

171	Electronic structure calculations with GPAW: a real-space implementation of the projector augmented-wave method. <i>Journal of Physics Condensed Matter</i> , <b>2010</b> , 22, 253202	1.8	1092
170	Tunability of the optical absorption in small silver cluster-polymer hybrid systems. <i>Journal of Chemical Physics</i> , <b>2010</b> , 132, 214301	3.9	8
169	Limits for n-type doping in In <sub>2</sub> O <sub>3</sub> and SnO <sub>2</sub> : A theoretical approach by first-principles calculations using hybrid-functional methodology. <i>Journal of Applied Physics</i> , <b>2010</b> , 108, 053511	2.5	52
168	Role of van der Waals forces in the adsorption and diffusion of organic molecules on an insulating surface. <i>Physical Review B</i> , <b>2009</b> , 80,	3.3	38
167	Effect of the surrounding oxide on the photoabsorption spectra of Si nanocrystals. <i>Physical Review B</i> , <b>2009</b> , 79,	3.3	20
166	Intrinsic n-type behavior in transparent conducting oxides: a comparative hybrid-functional study of In <sub>2</sub> O <sub>3</sub> , SnO <sub>2</sub> , and ZnO. <i>Physical Review Letters</i> , <b>2009</b> , 103, 245501	7.4	274
165	Linear-scaling self-consistent implementation of the van der Waals density functional. <i>Physical Review B</i> , <b>2009</b> , 79,	3.3	149
164	All-electron density functional theory and time-dependent density functional theory with high-order finite elements. <i>Journal of Chemical Physics</i> , <b>2009</b> , 131, 054103	3.9	43
163	Time-dependent density-functional theory in the projector augmented-wave method. <i>Journal of Chemical Physics</i> , <b>2008</b> , 128, 244101	3.9	158
162	Quantum well states, resonances and stability of metallic overlayers. <i>Journal of Physics Condensed Matter</i> , <b>2008</b> , 20, 315002	1.8	4
161	Photoabsorption spectra of small fullerenes and Si-heterofullerenes. <i>Journal of Chemical Physics</i> , <b>2008</b> , 128, 154307	3.9	21
160	Spin-Dependence in Asymmetric, V-Shaped-Notched Graphene Nanoribbons. <i>Journal of Low Temperature Physics</i> , <b>2008</b> , 153, 393-398	1.3	19
159	Quantitative chemical analysis of vacancy-solute complexes in metallic solid solutions by coincidence Doppler broadening spectroscopy. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , <b>2007</b> , 4, 3493-3496		10
158	Excited states of Na nanoislands on the Cu(111) surface. <i>Physical Review B</i> , <b>2007</b> , 75,	3.3	16
157	Image potential states of supported metallic nanoislands. <i>Physical Review B</i> , <b>2007</b> , 76,	3.3	17
156	Energetics of positron states trapped at vacancies in solids. <i>Physical Review B</i> , <b>2007</b> , 76,	3.3	37
155	Analysis of electron-positron momentum spectra of metallic alloys as supported by first-principles calculations. <i>Physical Review B</i> , <b>2007</b> , 75,	3.3	32
154	Electron-electron interaction in a two-dimensional electron gas: Bound states at low densities. <i>Physical Review B</i> , <b>2007</b> , 75,	3.3	1

153	Photoabsorption spectra of boron nitride fullerenelike structures. <i>Journal of Chemical Physics</i> , <b>2007</b> , 126, 214306	3.9	17
152	Gallium and nitrogen vacancies in GaN: Impurity decoration effects. <i>Physica B: Condensed Matter</i> , <b>2006</b> , 376-377, 424-427	2.8	15
151	First-principles calculation of positron states and annihilation at defects in semiconductors. <i>Physica B: Condensed Matter</i> , <b>2006</b> , 376-377, 971-974	2.8	7
150	Numerical study of bound states for point charges shielded by the response of a homogeneous two-dimensional electron gas. <i>Physical Review B</i> , <b>2006</b> , 74,	3.3	5
149	Modeling the momentum distributions of annihilating electron-positron pairs in solids. <i>Physical Review B</i> , <b>2006</b> , 73,	3.3	94
148	Giant vortices in rotating electron droplets. <i>Physical Review B</i> , <b>2006</b> , 73,	3.3	6
147	Interfacial oxide growth at silicon high-k oxide interfaces: First principles modeling of the Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> interface. <i>Journal of Applied Physics</i> , <b>2006</b> , 100, 043708	2.5	44
146	Finite-element implementation for electron transport in nanostructures. <i>Journal of Chemical Physics</i> , <b>2006</b> , 124, 054707	3.9	14
145	Direct evidence of impurity decoration of Ga vacancies in GaN from positron annihilation spectroscopy. <i>Physical Review B</i> , <b>2006</b> , 73,	3.3	81
144	Three real-space discretization techniques in electronic structure calculations. <i>Physica Status Solidi (B): Basic Research</i> , <b>2006</b> , 243, 1016-1053	1.3	82
143	Dissociation of VGa <sub>N</sub> complexes in HVPE GaN by high pressure and high temperature annealing. <i>Physica Status Solidi (B): Basic Research</i> , <b>2006</b> , 243, 1436-1440	1.3	7
142	Calculation of valence electron momentum densities using the projector augmented-wave method. <i>Journal of Physics and Chemistry of Solids</i> , <b>2005</b> , 66, 1128-1135	3.9	41
141	Vortex formation in quantum dots in high magnetic fields. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2005</b> , 26, 317-321	3	6
140	Characterization of deformed quantum dots by modeling single-electron-tunneling experiments. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2005</b> , 26, 477-481	3	1
139	Spin-dependent electron transport through a magnetic resonant tunneling diode. <i>Physical Review B</i> , <b>2005</b> , 71,	3.3	19
138	Positron localization effects on the Doppler broadening of the annihilation line: Aluminum as a case study. <i>Physical Review B</i> , <b>2005</b> , 72,	3.3	40
137	Stability of vortex structures in quantum dots. <i>Physical Review B</i> , <b>2005</b> , 71,	3.3	20
136	Self-consistent study of electron confinement to metallic thin films on solid surfaces. <i>Physical Review B</i> , <b>2005</b> , 71,	3.3	34

135	Charging mechanism for the bond elongation observed in suspended chains of gold atoms. <i>Physical Review B</i> , <b>2005</b> , 72,	3-3	12
134	Vacancy-impurity complexes in highly Sb-doped Si grown by molecular beam epitaxy. <i>Physical Review Letters</i> , <b>2005</b> , 94, 165501	7-4	30
133	Quantum size effects in Pb islands on Cu(111): Electronic structure calculations. <i>Physical Review B</i> , <b>2004</b> , 69,	3-3	38
132	Rectangular quantum dots in high magnetic fields. <i>Physical Review B</i> , <b>2004</b> , 69,	3-3	30
131	Vortex clusters in quantum dots. <i>Physical Review Letters</i> , <b>2004</b> , 93, 116802	7-4	58
130	Electron transport through quantum wires and point contacts. <i>Physical Review B</i> , <b>2004</b> , 70,	3-3	44
129	Broken symmetry in density-functional theory: Analysis and cure. <i>Physical Review B</i> , <b>2004</b> , 69,	3-3	27
128	Electron transport through monovalent atomic wires. <i>Physical Review B</i> , <b>2004</b> , 69,	3-3	119
127	Maximum-density-droplet formation in hard-wall quantum dots. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , <b>2004</b> , 22, 490-493	3	5
126	Nonequilibrium electron transport in two-dimensional nanostructures modeled using Green's functions and the finite-element method. <i>Physical Review B</i> , <b>2004</b> , 69,	3-3	30
125	Impurity effects in quantum dots: Toward quantitative modeling. <i>Physical Review B</i> , <b>2004</b> , 70,	3-3	104
124	Interaction effects in superconductor/normal quantum dot/superconductor structures. <i>Computational Materials Science</i> , <b>2004</b> , 30, 21-26	3-2	
123	Influence of electron-electron interactions on supercurrent in SNS structures. <i>Low Temperature Physics</i> , <b>2003</b> , 29, 546-550	0-7	3
122	MIKA: Multigrid-based program package for electronic structure calculations. <i>International Journal of Quantum Chemistry</i> , <b>2003</b> , 91, 171-176	2-1	35
121	Electronic structure calculations for 2-D quantum dots and laterally coupled quantum dot molecules in magnetic fields. <i>International Journal of Quantum Chemistry</i> , <b>2003</b> , 91, 490-497	2-1	5
120	Electronic structure of rectangular quantum dots. <i>Physical Review B</i> , <b>2003</b> , 67,	3-3	74
119	Testing of two-dimensional local approximations in the current-spin and spin-density-functional theories. <i>Physical Review B</i> , <b>2003</b> , 67,	3-3	46
118	Electronic resonance states in metallic nanowires during the breaking process simulated with the ultimate jellium model. <i>Physical Review B</i> , <b>2003</b> , 67,	3-3	9

117	Wigner molecules in polygonal quantum dots: A density-functional study. <i>Physical Review B</i> , <b>2003</b> , 67,	3.3	24
116	Electronic structure and prediction of magnetism in metallic nanowires. <i>Journal of Magnetism and Magnetic Materials</i> , <b>2002</b> , 249, 193-199	2.8	14
115	Stability of large vacancy clusters in silicon. <i>Physical Review B</i> , <b>2002</b> , 65,	3.3	54
114	Conductance oscillations in metallic nanocontacts. <i>Physical Review B</i> , <b>2002</b> , 66,	3.3	35
113	Model study of adsorbed metallic quantum dots: Na on Cu(111). <i>Physical Review B</i> , <b>2002</b> , 66,	3.3	11
112	Spontaneous magnetization of aluminum nanowires deposited on the NaCl(100) surface. <i>Physical Review B</i> , <b>2002</b> , 66,	3.3	28
111	Analysis of the shell- and supershell structures of metallic nanowires with jellium models. <i>Nanotechnology</i> , <b>2002</b> , 13, 363-368	3.4	14
110	Native defects and self-diffusion in GaSb. <i>Journal of Applied Physics</i> , <b>2002</b> , 91, 4988-4994	2.5	79
109	Multigrid method for electronic structure calculations. <i>Physical Review B</i> , <b>2001</b> , 63,	3.3	120
108	Shell and supershell structures of nanowires: A quantum-mechanical analysis. <i>Physical Review B</i> , <b>2001</b> , 64,	3.3	17
107	Electronic stopping calculated using explicit phase shift factors. <i>Physical Review B</i> , <b>2001</b> , 63,	3.3	23
106	First-principles calculations of interstitial boron in silicon. <i>Physical Review B</i> , <b>2000</b> , 61, 8155-8161	3.3	79
105	Point defects in silicon, first-principles calculations. <i>Computational Materials Science</i> , <b>2000</b> , 17, 365-373	3.2	5
104	Identification of Vacancy-Impurity Complexes in Highly n-Type Si. <i>Physical Review Letters</i> , <b>1999</b> , 82, 1883-1886	3.3	77
103	Electronic structure of cylindrical simple-metal nanowires in the stabilized jellium model. <i>Physical Review B</i> , <b>1999</b> , 59, 12652-12660	3.3	34
102	Microscopic identification of native donor Ga-vacancy complexes in Te-doped GaAs. <i>Physical Review B</i> , <b>1999</b> , 60, 1464-1467	3.3	30
101	Observation of Ga vacancies and negative ions in undoped and Mg-doped GaN bulk crystals. <i>Physica B: Condensed Matter</i> , <b>1999</b> , 273-274, 33-38	2.8	20
100	Theoretical studies of interstitial boron defects in silicon. <i>Physica B: Condensed Matter</i> , <b>1999</b> , 273-274, 268-270	2.8	1



99	The structure of vacancy-impurity complexes in highly n-type Si. <i>Physica B: Condensed Matter</i> , <b>1999</b> , 273-274, 463-467	2.8	4
98	Zabala, Puska, and Nieminen Reply:. <i>Physical Review Letters</i> , <b>1999</b> , 82, 3000-3000	7.4	7
97	First-Principles Calculations of Positron Annihilation in Solids. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 579, 249		3
96	Positron Lifetime Calculations of Hexagonal Metals with the True Geometry. <i>Physica Status Solidi (B): Basic Research</i> , <b>1998</b> , 206, 509-518	1.3	9
95	Effect of lattice structure on the positron annihilation with inner shell electrons. <i>Journal of Physics and Chemistry of Solids</i> , <b>1998</b> , 59, 55-59	3.9	18
94	Convergence of supercell calculations for point defects in semiconductors: Vacancy in silicon. <i>Physical Review B</i> , <b>1998</b> , 58, 1318-1325	3.3	210
93	Possible n-type dopants in diamond and amorphous carbon. <i>Computational Materials Science</i> , <b>1998</b> , 10, 351-355	3.2	16
92	Study of defects in electron irradiated CuInSe <sub>2</sub> by positron lifetime spectroscopy. <i>Journal of Applied Physics</i> , <b>1998</b> , 83, 71-78	2.5	30
91	Spontaneous Magnetization of Simple Metal Nanowires. <i>Physical Review Letters</i> , <b>1998</b> , 80, 3336-3339	7.4	83
90	Chlorine-impurity-related defects in ZnSe. <i>Physical Review B</i> , <b>1998</b> , 57, 12164-12168	3.3	12
89	Nitrogen-impurity-native-defect complexes in ZnSe. <i>Physical Review B</i> , <b>1998</b> , 57, 12174-12180	3.3	26
88	Momentum distributions of electron-positron pairs annihilating at vacancy clusters in Si. <i>Physical Review B</i> , <b>1998</b> , 57, 7621-7627	3.3	117
87	Metastability of the antistructure pair in GaAs. <i>Physical Review B</i> , <b>1997</b> , 55, 6914-6917	3.3	6
86	Correlation effects for electron-positron momentum density in solids. <i>Physical Review B</i> , <b>1997</b> , 56, 7136-7142	3.3	48
85	Nitrogen doping in ZnSe. <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , <b>1997</b> , 43, 1-4	3.1	4
84	Correlation effects for positron annihilation with core and semicore electrons. <i>Applied Surface Science</i> , <b>1997</b> , 116, 283-286	6.7	5
83	Two-component density-functional calculations for positrons trapped by defects in solids. <i>Applied Surface Science</i> , <b>1997</b> , 116, 293-299	6.7	
82	First-principles calculation of positron annihilation characteristics at metal vacancies. <i>Physical Review B</i> , <b>1996</b> , 54, 15016-15024	3.3	51

81	Theoretical and experimental study of positron annihilation with core electrons in solids. <i>Physical Review B</i> , <b>1996</b> , 54, 2397-2409	3.3	221
80	Calculation of positron states and annihilation in solids: A density-gradient-correction scheme. <i>Physical Review B</i> , <b>1996</b> , 53, 16201-16213	3.3	181
79	Ab initio study of fully relaxed divacancies in GaAs. <i>Physical Review B</i> , <b>1996</b> , 53, 3813-3819	3.3	96
78	Evaluation of some basic positron-related characteristics of SiC. <i>Physical Review B</i> , <b>1996</b> , 54, 2512-2517	3.3	84
77	Metastable defect complexes in GaAs. <i>Physical Review B</i> , <b>1996</b> , 54, 7909-7916	3.3	31
76	Method for the measurement of positron affinities and positron work functions suitable for both positive and negative work function materials. <i>Applied Surface Science</i> , <b>1995</b> , 85, 82-86	6.7	6
75	Positron annihilation and positron-electron correlation effects in high-Tc oxides. <i>Journal of Physics and Chemistry of Solids</i> , <b>1995</b> , 56, 1693-1694	3.9	3
74	Positron affinity for precipitates in reactor pressure vessel steels. <i>Nuclear Engineering and Design</i> , <b>1995</b> , 158, 149-156	1.8	25
73	Vacancy-formation energies for fcc and bcc transition metals. <i>Physical Review B</i> , <b>1995</b> , 51, 9526-9532	3.3	130
72	Electron-positron Car-Parrinello methods: Self-consistent treatment of charge densities and ionic relaxations. <i>Physical Review B</i> , <b>1995</b> , 52, 10947-10961	3.3	115
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64	Indium and phosphorus vacancies and antisites in InP. <i>Physical Review B</i> , <b>1994</b> , 49, 5253-5262	3.3	55

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53	Positron and electron energy levels in rare-gas solids. <i>Physical Review B</i> , <b>1992</b> , 46, 1278-1283	3.3	9
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47	Ab-initio calculation of positron annihilation rates in solids. <i>Journal of Physics Condensed Matter</i> , <b>1991</b> , 3, 3455-3469	1.8	76
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42	Electronic structures of point defects in III-V compound semiconductors. <i>Journal of Physics Condensed Matter</i> , <b>1989</b> , 1, 7347-7366	1.8	77
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32	Electron and positron energy levels in solids. <i>Physical Review B</i> , <b>1987</b> , 36, 7786-7794	3.3	92
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30	Electronic polarizability of small sodium clusters. <i>Physical Review B</i> , <b>1986</b> , 33, 4289-4290	3.3	51
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26	Electronic polarizability of small metal spheres. <i>Physical Review B</i> , <b>1985</b> , 31, 3486-3495	3.3	158
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